

Vishay High Power Products

HEXFRED® Ultrafast Soft Recovery Diode, 180 A





Lug terminal

Base

anode	
Q	

PRODUCT SUMMARY					
I _{F(AV)}	180 A				
V_{R}	400 V				
I _{F(DC)} at T _C	200 A at 100 °C				

FEATURES

- Very low Q_{rr} and t_{rr}
- · Lead (Pb)-free
- · Designed and qualified for industrial level



BENEFITS

- · Reduced RFI and EMI
- · Reduced snubbing

DESCRIPTION

HEXFRED® diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. An extensive characterization of the recovery behavior for different values of current, temperature and dl/dt simplifies the calculations of losses in the operating conditions. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Cathode to anode voltage	V _R		400	V	
		T _C = 25 °C	395		
Continuous forward current	I _F	T _C = 100 °C	200	Α	
Single pulse forward current	I _{FSM}	Limited by junction temperature	1200		
Non-repetitive avalanche energy	E _{AS}	$L = 100 \mu H$, duty cycle limited by maximum T_J	1.4	mJ	
Marian and a single sin		T _C = 25 °C	657	14/	
Maximum power dissipation	P_D	T _C = 100 °C	263	W	
Operating junction and storage temperature range	T _J , T _{Stg}		- 55 to + 150	°C	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA		400	-	-	
		I _F = 180 A		=	1.08	1.46	V
Maximum forward voltage	V_{FM}	I _F = 360 A	See fig. 1	=	1.22	1.8	
		I _F = 180 A, T _J = 125 °C		=	0.99	1.34	
Maximum reverse leakage current	I _{RM}	T _J = 125 °C, V _R = 400 V See fig. 2		-	-	4	mA
Junction capacitance	C _T	V _R = 200 V See fig. 3		-	370	500	pF
Series inductance	L _S	From top of terminal hole to mounting plane		-	6.0	-	nH

HFA180NH40PbF

Vishay High Power Products

HEXFRED® Ultrafast Soft Recovery Diode, 180 A



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time		T _J = 25 °C		-	90	140	20
See fig. 5	t _{rr}	T _J = 125 °C		-	280	440	ns
Peak recovery current		T _J = 25 °C		-	9	16	А
See fig. 6	IRRM	T _J = 125 °C	I _F = 135 A dI _F /dt = 200 A/μs	-	18	32	
Reverse recovery charge	$T_1 = 25 ^{\circ}\text{C}$	T _J = 25 °C	$V_{\rm R} = 200 \text{ V}$	-	300	950	nC
See fig. 7	T _J = 125 °C	-11 -200	-	2650	6300	110	
Peak rate of recovery current See fig. 8 dI _{(rec)M} /dt	dl/dt	T _J = 25 °C		-	300	=	- A/μs
	ui _{(rec)M} /dt	T _J = 125 °C		-	290	=	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T _J , T _{Stg}		- 55 to 150	°C	
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	0.19	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.05	C/VV	
Approximate weight				30	g	
Approximate weight				1.06	oz.	
Mounting torque	minimum			3 (26.5)		
Mounting torque	maximum			4 (35.4)	$N\cdotm$	
Terminal torque —	minimum			3.4 (30)	(lbf ⋅ in)	
	maximum			5 (44.2)		
Case style			HALF-PAK module	•	•	





HEXFRED® Ultrafast Soft Recovery Diode, 180 A

Vishay High Power Products

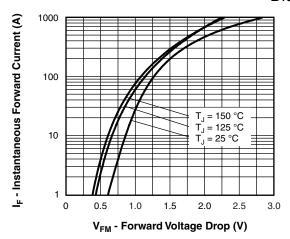


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current

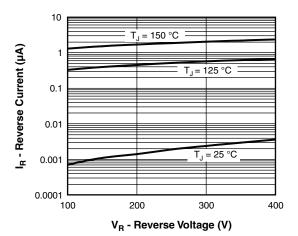


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

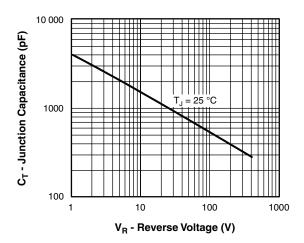


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

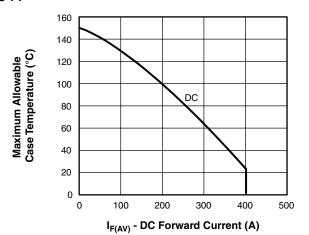


Fig. 4 - Maximum Allowable Case Temperature vs. DC Forward Current

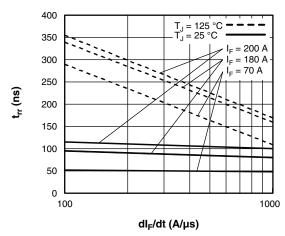


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt

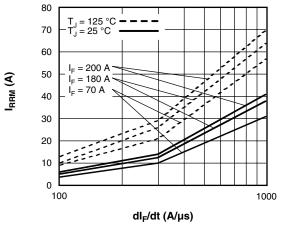


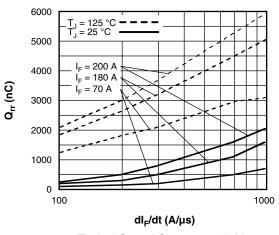
Fig. 6 - - Typical Recovery Current vs. dl_F/dt

HFA180NH40PbF

Vishay High Power Products

HEXFRED® Ultrafast Soft Recovery Diode, 180 A





10 000

200 A

180 A

70 A

1000

1000

1000

dl_E/dt (A/µs)

Fig. 7 - Typical Stored Charge vs. dI_F/dt

Fig. 8 - Typical $dl_{(rec)M}/dt$ vs. dl_F/dt

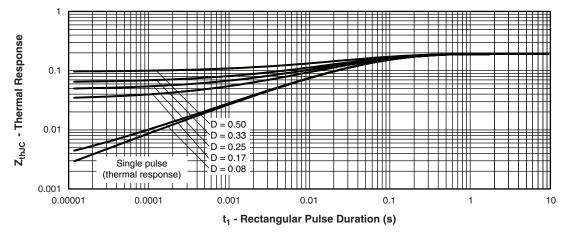


Fig. 9 - Maximum Thermal Impedance Z_{thJC} Characteristics



HEXFRED® Ultrafast Soft Recovery Diode, 180 A

Vishay High Power Products

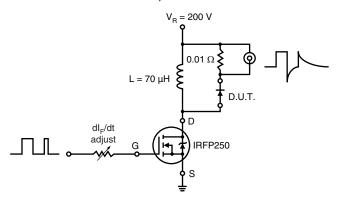
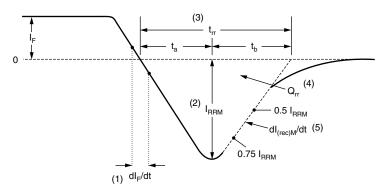


Fig. 10 - Reverse Recovery Parameter Test Circuit



- (1) dI_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 11 - Reverse Recovery Waveform and Definitions

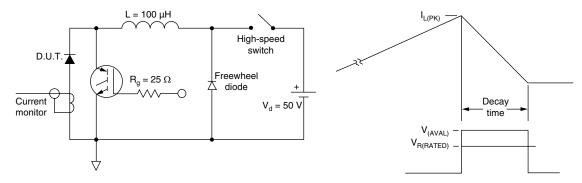


Fig. 12 - Avalanche Test Circuit and Waveforms

HFA180NH40PbF

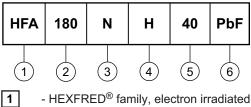
Vishay High Power Products

HEXFRED® Ultrafast Soft Recovery Diode, 180 A



ORDERING INFORMATION TABLE

Device code



- Average current rating

- N = Not isolated

- H = HALF-PAK

- Voltage rating (400 V)

- Lead (Pb)-free

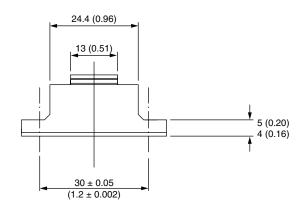
LINKS TO RELATED DOCUMENTS				
Dimensions	http://www.vishay.com/doc?95020			

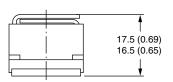


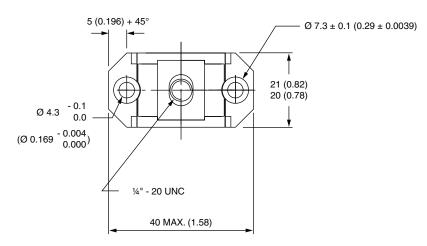
Vishay Semiconductors

D-67 HALF-PAK

DIMENSIONS in millimeters (inches)









Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Vishay:

VS-HFA180NH40PBF